SN74CBT1G66 SINGLE FET BUS SWITCH

DBV OR DCK PACKAGE

(TOP VIEW)

A

B 🛛 2

GND 3

5 V_{CC}

4 🛛 OE

SCDS110 - JULY 2000

- 5-Ω Switch Connection Between Two Ports
- CMOS-Compatible Control Input Levels
- Package Options Include Plastic Small-Outline Transistor (DBV, DCK) Packages

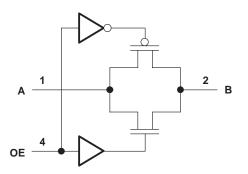
description

The SN74CBT1G66 features a single high-speed line switch. The switch is disabled when the output-enable (OE) input is low.

The SN74CBT1G66 is characterized for operation from -40°C to 85°C.

FUNCTION TABLE				
INPUT OE	FUNCTION			
Н	A port = B port			
L	Disconnect			

logic diagram (positive logic)





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCT PREVIEW information concerns products in the formative or design phase of development. Characteristic data and other specifications are design goals. Texas Instruments reserves the right to change or discontinue these products without notice.



Copyright © 2000, Texas Instruments Incorporated

SN74CBT1G66 SINGLE FET BUS SWITCH

SCDS110 - JULY 2000

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V _{CC}	
Continuous channel current	
Input clamp current, I_{IK} ($V_{I/O} < 0$)	
Package thermal impedance, θ_{JA} (see Note 2): DBV package	
DCK package	
Storage temperature range, T _{stg} –65°C to 15	o∘C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 3)

			MIN	MAX	UNIT
Vcc	V _{CC} Supply voltage		2.3	5.5	V
V _{I/O}	/I/O I/O port voltage		0	VCC	V
VIH	H High-level input voltage		$0.7 \times V_{CC}$		V
VIL	L Low-level input voltage			$0.3 \times V_{CC}$	V
VIN	V _{IN} Control input voltage		0	5.5	V
t _r /t _f	Control input transition rise/fall time	$V_{CC} = 2.3 \text{ V to } 3.6 \text{ V}$		10	ns
		$V_{CC} = 4.5 V \text{ to } 5.5 V$		5	
TA	T _A Operating free-air temperature		-40	85	°C

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TE	ST CONDITIONS	V _{CC}	MIN TYP [‡]	MAX	UNIT
VIK	Ij = -18 mA		4.5 V		-1.2	V
lı lı	0 ≤ VI ≤ 5.5 V		0 to 5.5 V		±1	μΑ
l _{off}	$0 \le A \text{ or } B \le 4.5 \text{ V}$		$V_{CC} = 0$		10	μΑ
I _{OZ}	$0 \le A \text{ or } B \le V_{CC}$		2.3 V to 5.5 V		±10	μΑ
ron	$V_{\parallel} = 0$	lı = 8 mA	2.3 V	5	12	
	VI = 2.3 V	ij = 0 IIIA	2.3 V	13	30	
	VI = 0	1. 0.4 mA	3 V	4	9	
	VI = 3 V	Iι = 24 mA	3 V	10	20	Ω
	V _I = 0,	lı = 30 mA		3	7	
	V _I = 2.4 V,	lı = 15 mA	4.5 V	5	12	
	V _I = 4.5 V,	l _l = 30 mA		7	15	
ICC	$V_I = V_{CC}$ or GND	I <mark>O</mark> = 0	5.5 V		10	μΑ
Ci			0			рF
C _{io}			5 V			pF

[‡] All typical values are at $V_{CC} = 5 V$, $T_A = 25^{\circ}C$.

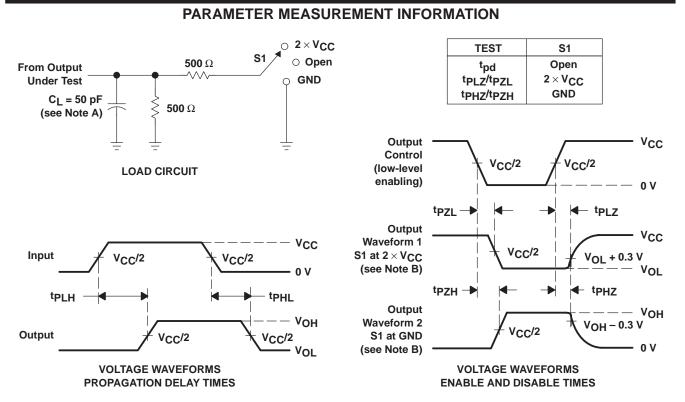


SN74CBT1G66 SINGLE FET BUS SWITCH

SCDS110 - JULY 2000

switching characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	FROM (INPUT)	ТО (ОՍТРИТ)	V _{CC} = 2.5 V ± 0.2 V	V _{CC} = 3.3 V ± 0.3 V	V _{CC} = 5 V ± 0.5 V	UNIT
			MIN MAX	MIN MAX	MIN MAX	
^t pd	A or B	B or A				ns
t _{en}	OE	A or B				ns
tdis						



- NOTES: A. CL includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_f \leq 2.5 ns, t_f \leq 2.5 ns.
 - D. The output is measured with one input transition per measurement.
 - E. t_{PIZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. tpLH and tpHL are the same as t_{pd} .

Figure 1. Load Circuit and Voltage Waveforms



IMPORTANT NOTICE

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgment, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

Customers are responsible for their applications using TI components.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.

Copyright © 2000, Texas Instruments Incorporated